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Date:	August 13, 2004		
To:	US Patent & Trademark Office Fax: 703-872-9306		
From:	David E. Steuber Tel: 408/982-8201 Fax: 408/982-8210		
Pages	9 (including cover sheet)		
Inventors:	William R. Entley et al.		
Title:	In Situ Plasma Process To Remove Fluorine Residues From The Interior Surfaces Of A CVD Reactor		
Application	10/003,908	Confirmation	7739
Examiner:	Anita Karen Alanko		

Enclosed for filing in the above-identified application are the following:

Transmittal Letter (1 page); and
Amendment After Final (7 pages)

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**TRANSMITTAL
FORM**

(to be used for all correspondence after initial filing)

Total Number Of Pages In This Submission

8

Application Number

10/003,908

Filing Date

11/1/2001

First Named Inventor

William R. Entley

Group Art Unit

1765

Examiner Name

Anita Karen Alanko

Attorney Docket No.

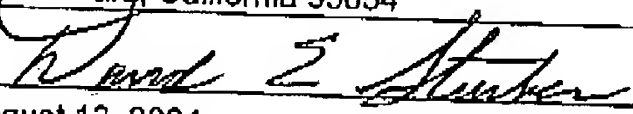
NVS013 US

ENCLOSURES (check all that apply)☐ Fee Transmittal Form (1 page in duplicate)☐ Fee Attached - Credit Card Payment Form (1 page)☒ Amendment Reply☒ After Final (7 pages)☐ Affidavits/declarations☐ Extension of Time Request☐ Express Abandonment Request☐ Information Disclosure Statement☐ Certified Copy of Priority Document(s)☐ Response to Missing Parts/Incomplete Application☐ Response to Missing Parts under 37 CFR 1.52 or 1.53☐ Assignment Papers (for an Application)☐ Drawing(s)☐ Licensing-related Papers☐ Petition☐ Petition to Convert to a Provisional Application☐ Power of Attorney, Revocation of Previous Powers; And Statement Under 37 CFR 3.73(b)☐ Terminal Disclaimer☐ Request for Refund☐ CD, Number of CD(s) _____☐ After Allowance Communication to Group☐ Appeal Communication to Board of Appeals and Interferences☐ Appeal Communication to Group (Appeal Notice, Brief, Reply Brief)☐ Proprietary Information☐ Status Letter☐ Other Enclosure(s) (please identify below):

Remarks

SIGNATURE OF APPLICANT, ATTORNEY OR AGENTFirm
or
Individual NameDavid E. Steuber (Reg. No. 25,557)
Silicon Valley Patent Group LLP
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Santa Clara, California 95054

Signature

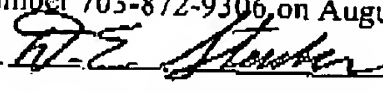


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Attorney for Applicant(s)

Date of Signature

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Appl. No.	10/003,908	Confirmation No.	7739
First Inventor	William R. Entley	Filing Date	11/1/2001
Tech. Center/ Art Unit	1765	Examiner	Anita Karen Alanko
Title:	In Situ Plasma Process To Remove Fluorine Residues From The Interior Surfaces Of A CVD Reactor		
Docket No.:	NVS013 US	Customer No.:	34036

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Santa Clara, California
August 13, 2004MAIL STOP AF
COMMISSIONER FOR PATENTS
P.O. Box 1450
Alexandria, VA 22313-1450AMENDMENT AFTER FINAL ACTION

Dear Sir:

In response to Office Action dated May 19, 2004, please amend the above-identified application as follows.

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 6 of this paper.